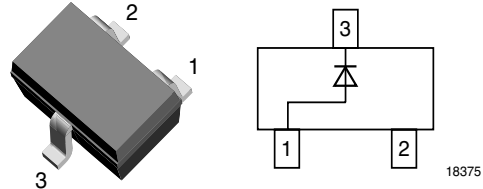


RF PIN Diode - Single in SOT-323

Description

Characterized by a very low reverse Capacitance the PIN Diode BAR63V-03W was designed for RF signal tuning. As a function of the forward bias current the forward resistance (rf) can be adjusted to less than 1Ω while the low reverse capacitance offers a high isolation. Typical applications for this PIN Diodes are wireless, mobile and TV-systems.



Features

- Low forward resistance
- Very small reverse capacitance
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Mechanical Data

Case: SOT-323 Plastic case

Weight: approx. 6.0 mg

Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box

GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

Applications

For frequency up to 3 GHz

RF-signal tuning

Mobile, wireless and TV-Applications

Parts Table

Part	Ordering code	Marking	Remarks
BAR63V-03W	BAR63V-03W-GS18 or BAR63V-03W-GS08	CW3	Tape and Reel

Absolute Maximum Ratings

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	50	V
Forward current		I_F	100	mA
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	- 55 to + 150	$^\circ\text{C}$

Electrical Characteristics

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Reverse voltage	$I_R = 10 \text{ } \mu\text{A}$	V_R	50			V
Reverse current	$V_R = 35 \text{ V}$	I_R			10	nA
Forward voltage	$I_F = 100 \text{ mA}$	V_F			1.2	V
Diode capacitance	$f = 1 \text{ MHz}, V_R = 0$	C_D		0.28		pF
	$f = 1 \text{ MHz}, V_R = 5 \text{ V}$	C_D		0.23	0.3	pF

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward resistance	$f = 100 \text{ MHz}, I_F = 1 \text{ mA}$	r_f		2.0		Ω
	$f = 100 \text{ MHz}, I_F = 5 \text{ mA}$	r_f		1.1	2.0	Ω
	$f = 100 \text{ MHz}, I_F = 10 \text{ mA}$	r_f		0.9		Ω
Charge carrier life time	$I_F = 10 \text{ mA}, I_R = 6 \text{ mA}, i_R = 3 \text{ mA}$	t_{rr}		115		ns

Typical Characteristics (Tamb = 25 °C unless otherwise specified)

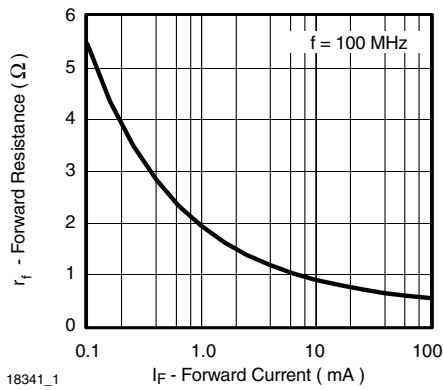


Figure 1. Forward Resistance vs. Forward Current

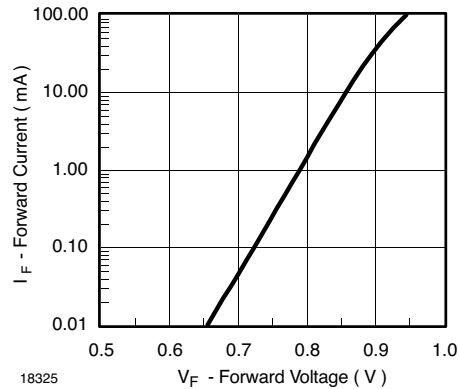


Figure 3. Forward Current vs. Forward Voltage

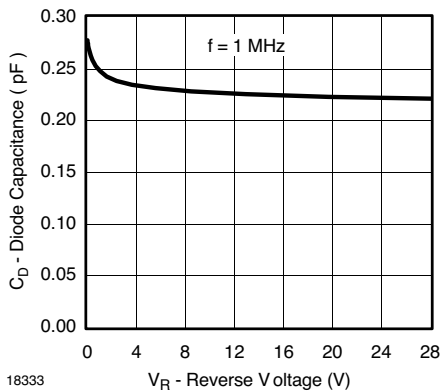


Figure 2. Diode Capacitance vs. Reverse Voltage

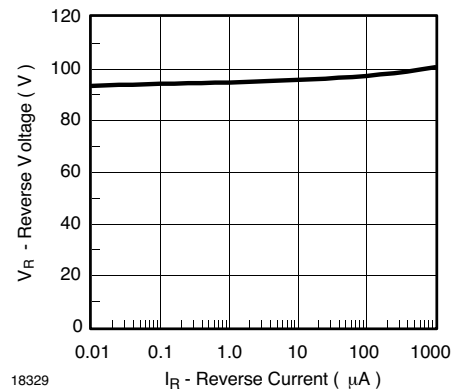


Figure 4. Reverse Voltage vs. Reverse Current

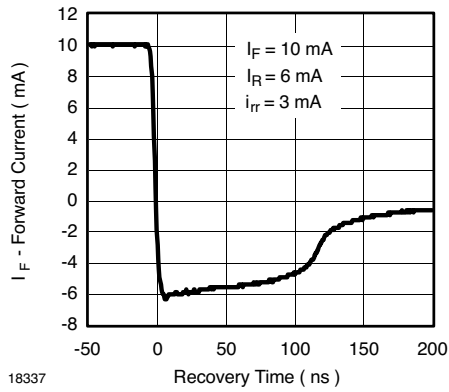
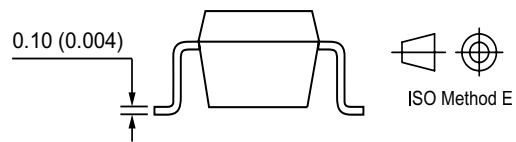
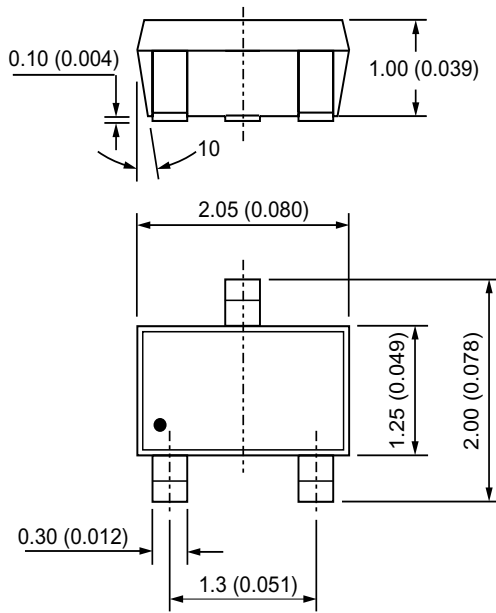
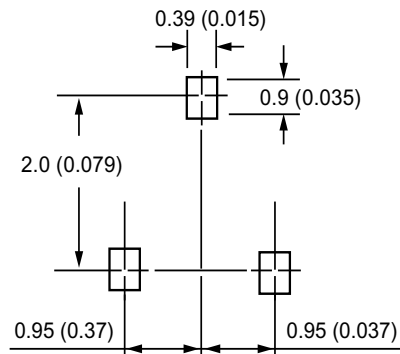


Figure 5. Typical Charge Recovery Curve

Package Dimensions in mm (Inches)



Mounting Pad Layout



96 12236

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

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Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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